

Features

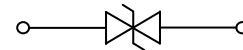
- 40 Watts peak pulse power ($t_p = 8/20\mu s$)
- DFN1006 (0402) package
- Bidirectional configurations
- Low clamping voltage
- Low leakage current
- Low capacitance ($C_j=2.7pF$ typ.)
- Protection one data/power line to:
 - IEC 61000-4-2 $\pm 10kV$ contact $\pm 15kV$ air
 - IEC 61000-4-4 (EFT) 40A (5/50ns)
 - IEC 61000-4-5 (Lightning) 3.5A (8/20 μs)
- RoHS compliant



DFN1006 (0402)

Applications

- Audio Line, Speaker, Headset, Microphone Protection
- Human Interface Devices (Keyboard, Touchpad, Buttons)
- USB2.0 Protection



Schematic Diagram

Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power ($T_P=8/20\mu S$)	P_{PP}	40	W
ESD Contact/Air Discharge (IEC-61000-4-2)	V_{ESD}	10/15	kV
Peak Pulse Current ($t_P = 8/20\mu S$)	I_{PP}	3.5	A
Junction Temperature	T_J	-55 to +125	$^\circ C$
Storage Temperature	T_{STG}	-55 to +150	$^\circ C$

Electrical Characteristics ($T_A=25^\circ C$ unless otherwise specified)

Parameter	mbol	Condition	Min	Typ	Max	Unit
Reverse stand-off Voltage	V_{RWM}	-	-	-	5.0	V
Reverse Breakdown Voltage	V_{BR}	$I_T=1mA$	5.5	6.5	-	V
Reverse Leakage Current	I_R	$V_R=5.0V$	-	5	100	nA
Clamping Voltage (IEC 61000-4-5)	V_C	$I_{PP}=3.5A$	-	-	11.5	V
Trigger Voltage (IEC 61000-4-2)	V_T	$V_{ESD}=8kV$	-	80	-	V
Clamping Voltage (IEC 61000-4-2)	V_C	$V_{ESD}=8kV$	-	12	-	V
Junction Capacitance	C_J	$V_R=0V, f=1MHz$	-	2.7	3.5	pF

Typical Characteristic Curves

Fig.1 Peak Pulse Power Rating Curve

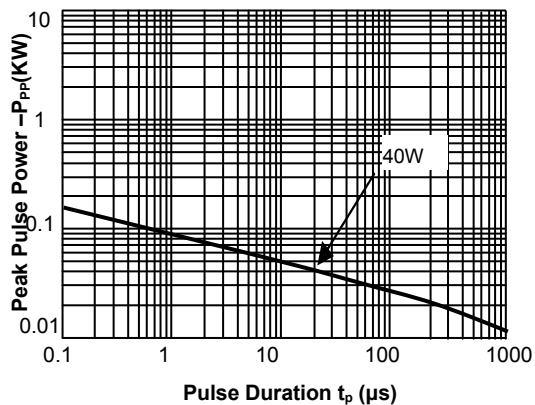


Fig.2 Pulse Derating Curve

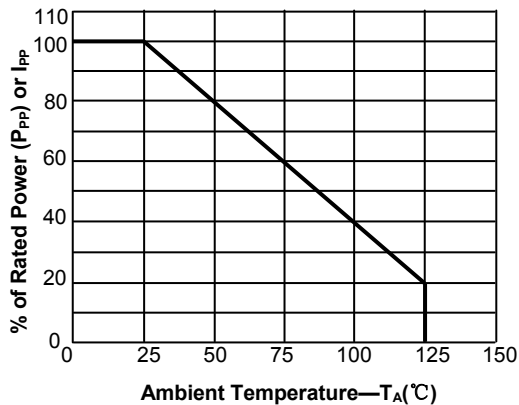


Fig.3 Pulse Waveform-8/20 μs

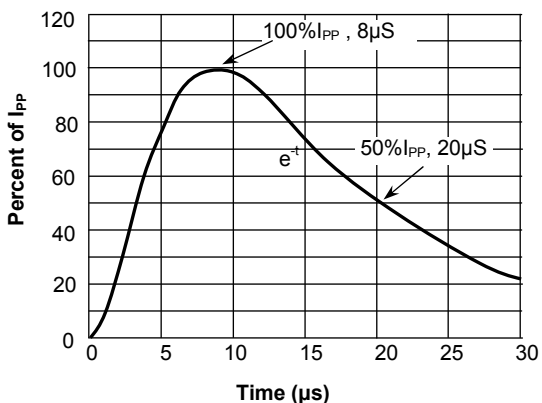
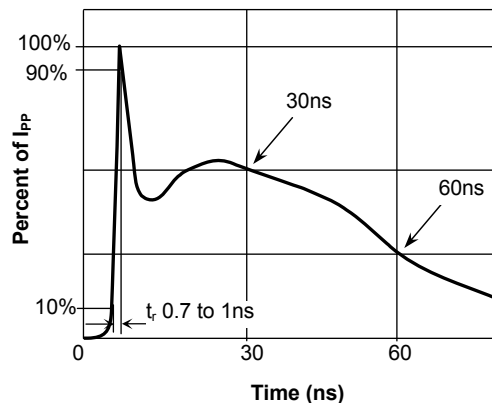
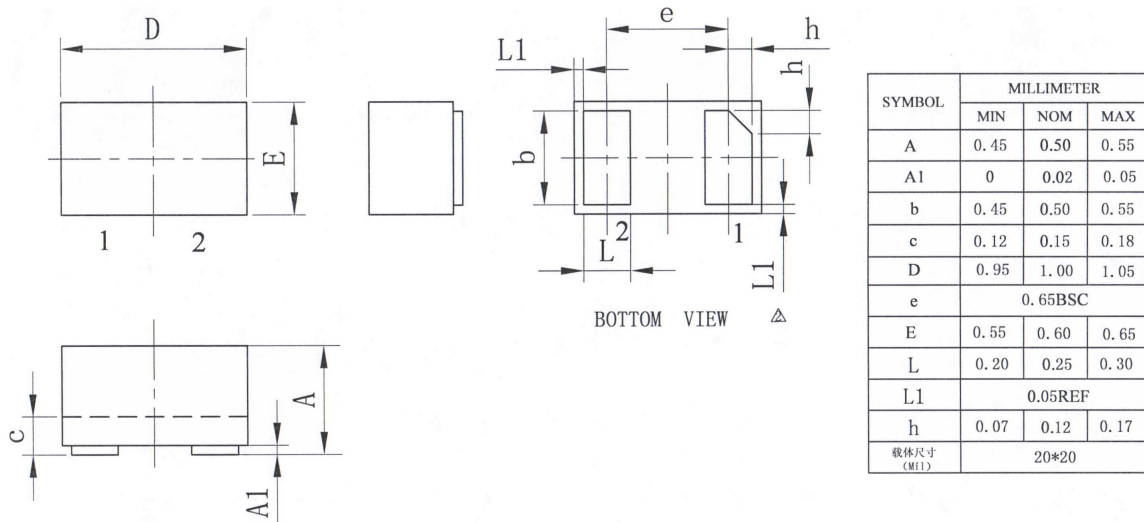


Fig.4 Pulse Waveform-ESD(IEC61000-4-2)



Product Dimensions



Order Information

Device	Marking	Carrier	Quantity	HSF Status
SPESLC5VD1006S-2B	5S	Tape & Reel	12000pcs / Reel	RoHS compliant